

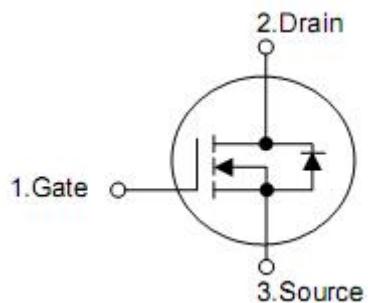
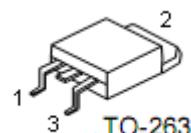
1. Features

- $R_{DS(ON)}=7.2\text{m}\Omega(\text{typ}) @ V_{GS}=10\text{V}$
- Lead free and green device available
- Low Rds-on to minimize conductive loss
- High avalanche current

2. Applications

- Power supply
- DC-DC converters

3. Pin configuration



Pin	Function
1	Gate
2	Drain
3	Source

4. Ordering Information

Part Number	Package	Brand
KNB3308B	TO-263	KIA

5. Absolute maximum ratings

Parameter	Symbol	Maximum	Units
Drain-source voltage	V_{DSS}	80	V
Gate-source voltage	V_{GSS}	± 25	V
Continuous drain current	I_D^3	80	A
		65	A
Pulse drain current	I_{DP}^4	320	A
Avalanche current	I_{AS}^5	40	A
Avalanche energy	E_{AS}^5	440	mJ
Maximum power dissipation	P_D	210	W
		105	W
Junction & storage temperature range	T_J, T_{STG}	-55~175	°C

6. Thermal characteristics

Parameter	Symbol	Typical	Units
Thermal resistance-junction to case	$R_{\theta jc}$	0.72	°C/W
Thermal resistance-junction to ambient	$R_{\theta ja}$	62.5	

7. Electrical characteristics

($T_A=25^\circ\text{C}$,unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Static characteristics						
Drain-source breakdown voltage	BV_{DSS}	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=250\mu\text{A}$	80	-	-	V
Zero gate voltage drain current	I_{DSS}	$V_{\text{DS}}=64\text{V}, V_{\text{GS}}=0\text{V}$	-	-	1	μA
		$T_J=125^\circ\text{C}$	-	-	100	
Gate threshold voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=250\mu\text{A}$	2	3	4	V
Gate leakage current	I_{GSS}	$V_{\text{GS}}=\pm 25\text{V}, V_{\text{DS}}=0\text{V}$	-	-	± 100	nA
Drain-source on-state resistance	$R_{\text{DS}(\text{on})}^1$	$V_{\text{GS}}=10\text{V}, I_{\text{D}}=40\text{A}$	-	7.2	9	$\text{m}\Omega$
Diode characteristics						
Diode forward voltage	V_{SD}^1	$I_{\text{SD}}=40\text{A}, V_{\text{GS}}=0\text{V}$	-	0.8	1.5	V
Diode continuous forward current	I_{S}^3		-	-	80	A
Reverse recovery time	t_{rr}	$I_{\text{F}}=40\text{A}, dI/dt=100\text{A}/\mu\text{s}$	-	60	-	nS
Reverse recovery charge	Q_{rr}		-	122	-	nC
Dynamic characteristics²						
Gate resistance	R_{G}	$V_{\text{GS}}=0\text{V}, V_{\text{DS}}=0\text{V}, F=1\text{MHz}$	-	1.6	-	Ω
Input capacitance	C_{iss}	$V_{\text{GS}}=0\text{V}, V_{\text{DS}}=25\text{V}, F=1.0\text{MHz}$	-	3650	-	pF
Output capacitance	C_{oss}		-	420	-	
Reverse transfer capacitance	C_{rss}		-	180	-	
Turn-on delay time	$t_{\text{d}(\text{ON})}$	$V_{\text{DD}}=37.5\text{V}, I_{\text{D}}=40\text{A}, V_{\text{GS}}=10\text{V}, R_{\text{G}}=6.8\Omega$	-	21	-	nS
Turn-on rise time	t_{r}		-	64	-	
Turn-off delay time	$t_{\text{d}(\text{OFF})}$		-	66	-	
Turn-off fall time	t_{f}		-	40	-	
Gate charge characteristics²						
Total gate charge	Q_{g}	$V_{\text{DS}}=37.5\text{V}, V_{\text{GS}}=10\text{V}, I_{\text{D}}=40\text{A}$	-	75	-	nC
Gate-source charge	Q_{gs}		-	10	-	
Gate-drain charge	Q_{gd}		-	38	-	

Note:1. Pulse test; pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$.

2.Guaranteed by design,not subject to production testing.

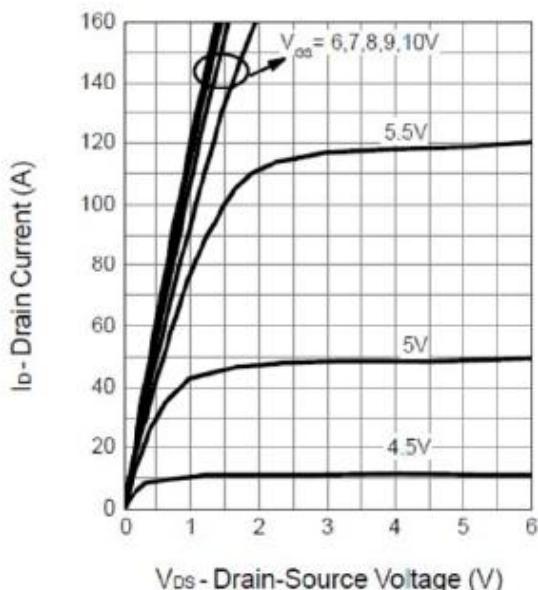
3.Package limitation current is 50A. Calculated continuous current based on maximum allowable junction temperature.

4.Repetitive rating, pulse width limited by max junction temperature.

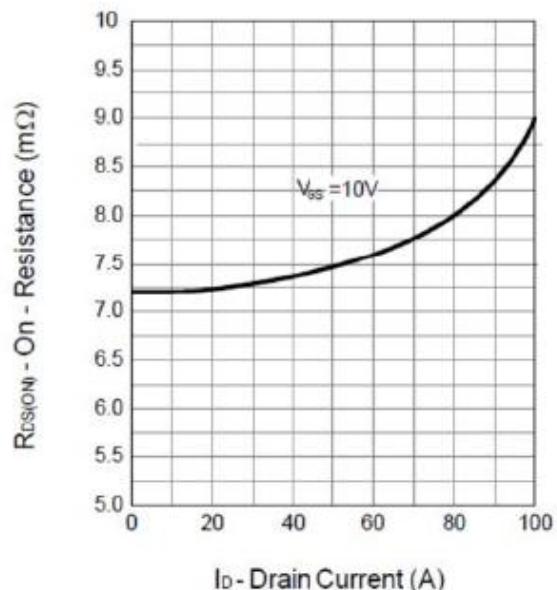
5.Starting $T_J=25^\circ\text{C}$, $L=0.5\text{mH}$, $V_{\text{DD}}=50\text{V}, I_{\text{AS}}=42\text{A}$.

8. Test circuits and waveforms

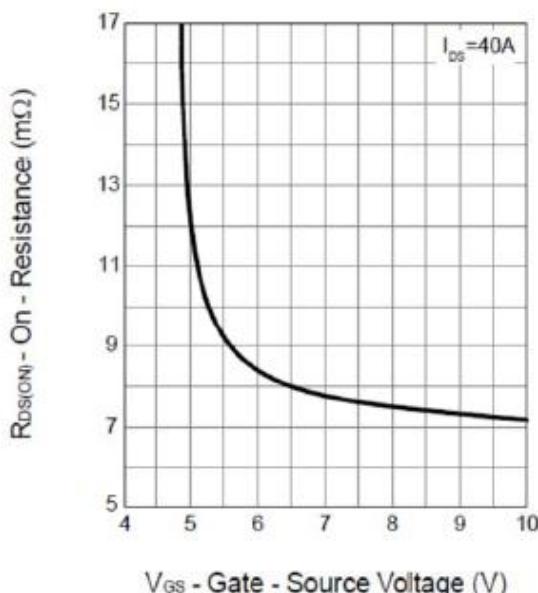
Output Characteristics



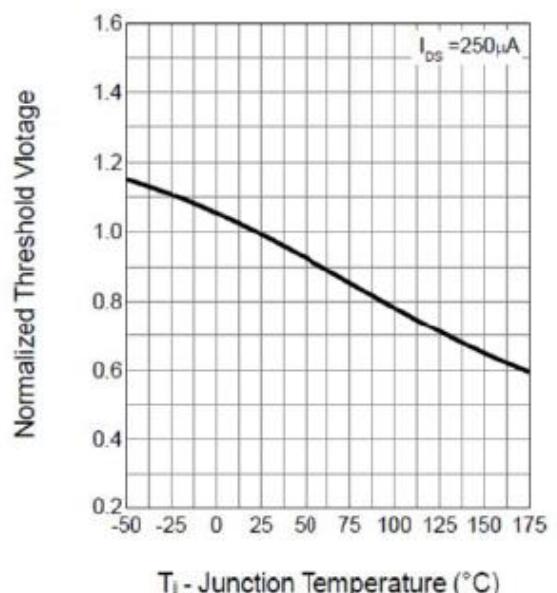
Drain-Source On Resistance

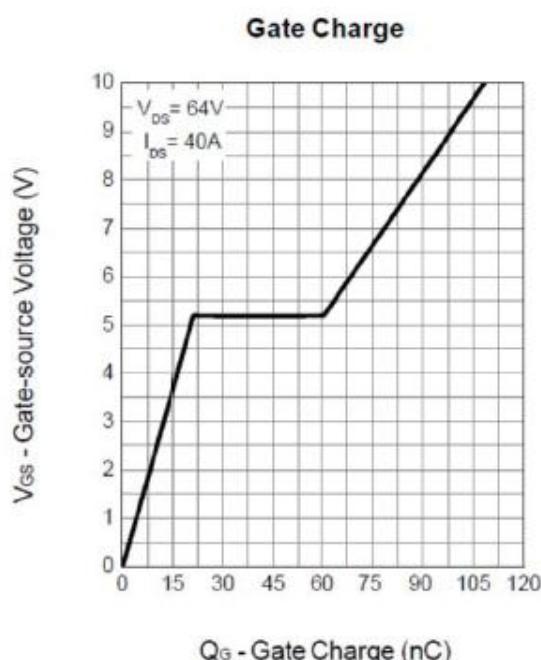
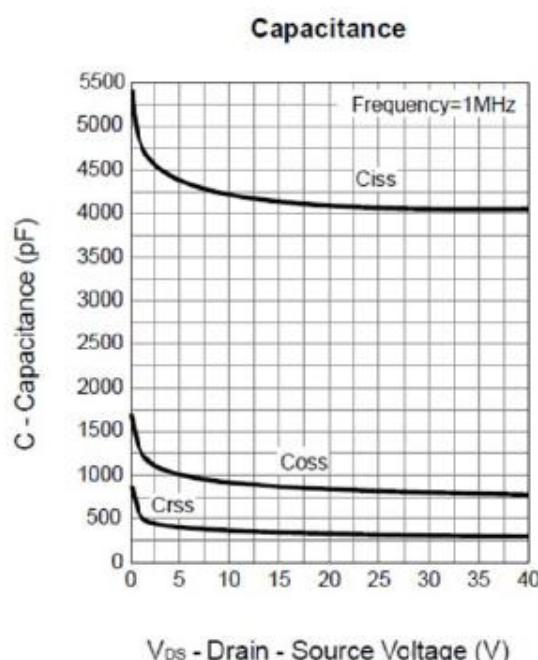
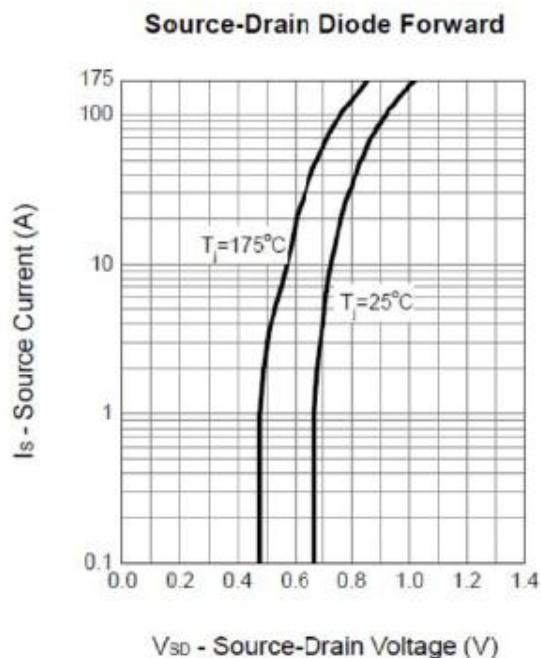
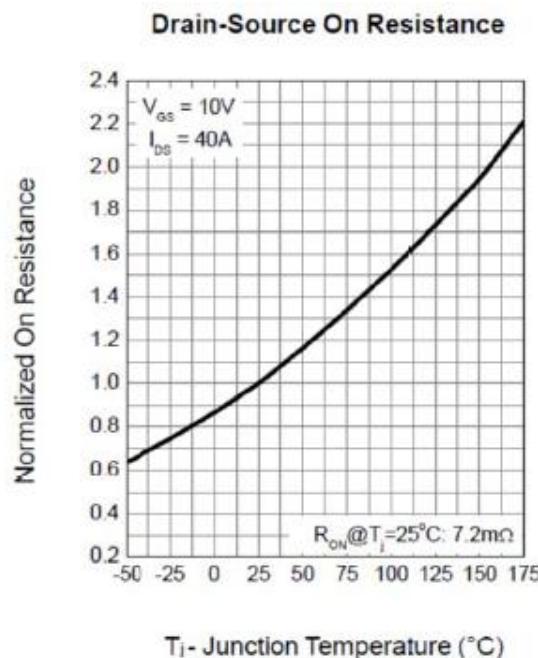


Drain-Source On Resistance

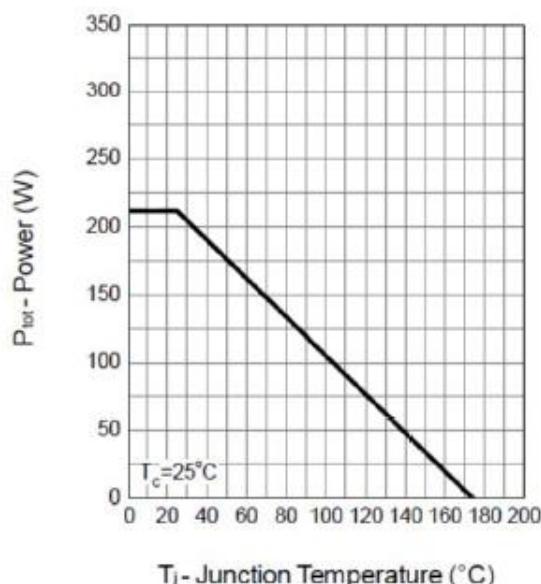


Gate Threshold Voltage

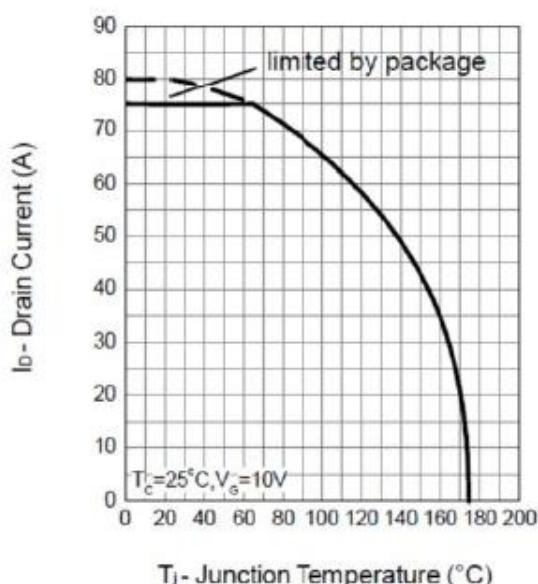




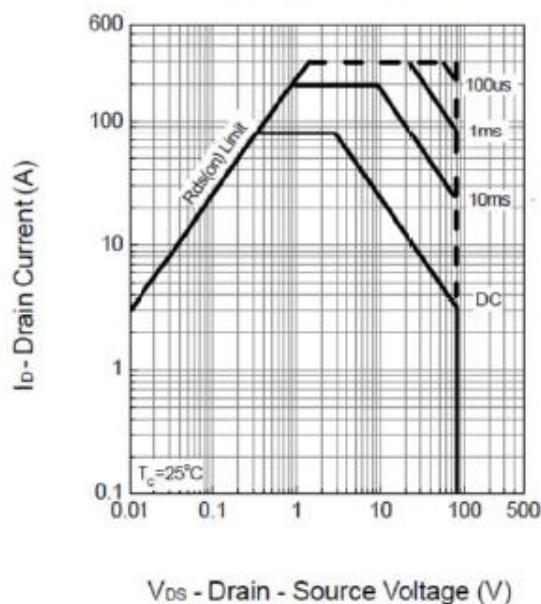
Power Dissipation



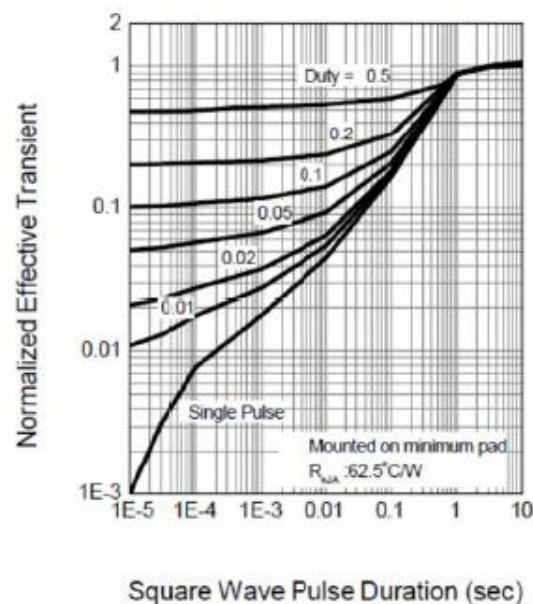
Drain Current



Safe Operation Area



Thermal Transient Impedance



V_{DS} - Drain - Source Voltage (V)

Square Wave Pulse Duration (sec)

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